

Condensation energy, charge ordering and inter-layer coupling in cuprates

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The correlation between the condensation energy and the critical temperature is studied within a charge ordered superlattice bilayer model in which pairing is supported by inter-layer Coulomb energy gain (potential energy driven superconductivity). The 2D pair-condensate can be characterized by a charge ordered state with a "checkerboard" like pattern seen by scanning tunneling microscopy. The drop of the c -axis dielectric screening can be the primary source of the condensation energy at optimal doping. We find that Coulomb energy gain occurs along the c -axis, which is proportional to the measured condensation energy (U_0) and to T_c : $E_c^{3D} \approx 2(\xi_{ab}/a_0 + 1)^2 U_0 \approx k_B T_c$ and is due to inter-layer charge complementarity (charge asymmetry of the boson condensate) where ξ_{ab} is the coherence length of the condensate and $a_0 \approx 3.9\text{\AA}$ is the in-plane lattice constant. The static c -axis dielectric constant ϵ_c is calculated for various cuprates and compared with the available experimental data. *PACS numbers:* 74.20.-z, 74.25.-q, 74.72.-h

Despite the enormous amount of effort spent in the last decades in resolving the fundamental physics behind high temperature superconductivity (HTSC) the mechanism is still puzzling [1]. It is more or less generally accepted now that the conventional electron-phonon pairing mechanism cannot explain cuprate superconductivity, because as high a transition temperature as 164K (the record T_c up to now [2]) cannot be explained by the energy scale of lattice vibrations without leading to lattice instability [1]. It is, however, already well established that much of the physics related to HTSC is in 2D nature, one of the basic questions to be answered still in the future is whether HTSC is a strictly 2D phenomenon or should be described by a 3D theory including all the 2D features of superconductivity.

The systematic dependence of the transition temperature T_c on the c -axis structure and, in particular, on the number of CuO_2 planes in multilayer blocks are strongly in favour of the 3D character of HTSC. Variation of the thickness of ultrathin artificial HTSC compounds leads to the significant change of T_c supporting the importance of IL coupling in cuprates [3]. It has also been shown recently that the c -axis transport of the hole-content to the doping site in the charge reservoir in the normal state (NS) of cuprates may be important in understanding HTSC [4]. Despite of the significant amount of published works which support the importance of the 3D character of HTSC 2D theories rule the literature in the last years [1]. This is partly due to the failure of the inter-layer (IL) tunneling model of Anderson [5,6] which was the prominent 3D theory of HTSC. Another reason could be that no straightforward dependence of T_c can be seen on the IL distance and on other 3D parameters of cuprates. Therefore the 3D character of HTSC is more complicated and needs more theoretical and experimental work in the future.

In this paper we propose a simple phenomenological model for explaining the 3D character of HTSC in cuprates supported by calculations. We would like to study the magnitude of direct Coulomb interaction between charge ordered square superlattice layers as a possible source of pairing interaction. Our intention is to understand HTSC within the context of an IL Coulomb-mediated mechanism. The IL charging energy we wish to calculate depends on the IL spacing (d), the IL dielectric constant ϵ_c , the hole content p and the size of the superlattice. A large body of experimental data are collected which support our model. A consistent picture is emerged on the basis of the careful analysis of this data set. Finally we calculate the static c -axis dielectric constant ϵ_c (that is normal to the ab -plane) for various cuprates which are compared with the available experimental observations.

We propose to examine the following charge ordered superlattice model of pair condensation: A pair of charge carriers ($2e$) can in principle be distributed over $2/0.16 = 12.5$ CuO_2 unit cells in a square lattice layer if the $2e$ pair is composed of the optimal hole content $p_0 \approx 0.16/\text{CuO}_2$ at optimal doping [7]. However, allowing the phase separation of hole-anti-hole pairs, every second unit cell is occupied by $-0.16e$ (anti-hole), and the rest is empty (holes, $+0.16e$), therefore we have 25 unit cells for a condensed pair of charge carriers (FIG 1., that is the unit lattice of the pair condensate in the 5×5 supercell model). Therefore, $2p_0 = -0.32e$ hole charge condenses to every second hole forming anti-hole sites. The 25 lattice sites provide the hole content of $25 \times 0.16e = 4e$ and therefore $2e$ excess charge in the anti-hole sites. The other $2e$ charge is used for neutralizing the holes at the anti-hole sites. In other words a Cooper wave-function can be distributed on a 5×5 superlattice with a node of $-0.16e$ in every anti-hole site. The remarkable feature is that

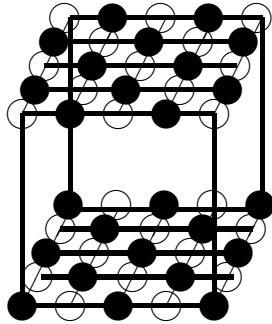


FIG. 1. The charge ordered state of the hole-anti-hole condensate in the $4a_0 \times 4a_0$ charge ordered bilayer superlattice model. Note the charge asymmetry between the adjacent layers. The bilayer can accommodate a pair of boson condensate ($4e$). The inter-layer charge complementarity of the charge ordered state is crucial for getting inter-layer Coulomb energy gain.

the size of the 5×5 condensate (four lattice spacings, $4a_0 \approx 15.5\text{\AA}$) is comparable with the measured small coherence length ξ_{ab} of single-layer cuprates ($\xi_{ab} \sim 10\text{\AA}$ to 20\AA) [8]. ξ_{ab} can directly be related to the characteristic size of the wave-pocket of the local Cooper pair (coherence area) [8]. The *charge ordered superlattice bilayer* (COSB) model can in principle be applied not only for $p_0 \approx 0.16e$ but also for the entire doping regime.

IL Coulomb energy gain occurs only in that case when holes in one of the layers are in proximity with anti-holes in the other layer (FIG 1, IL *electrostatic complementarity*, bilayer 5×5 ($4a_0 \times 4a_0$) model). An important feature is then that the boson condensate can be described by an IL *charge asymmetry*. The IL coupling of the boson-boson pairs in the bilayer 5×5 model naturally suggests the effective mass of charge carriers $m^* \approx 4m_e$, as it was found by measurements [17]. The 5×5 model can be generalized to represent a $N \times N$ coherence area where N is the real space periodicity of the superlattice. In the $N \times N$ superlattice model the hole and anti-hole partial charges at each CuO_2 lattice sites are $q = \pm 4e/N^2$ [16]. Important to note that the charge sum rule holds for the characteristic bilayer with a coherence area $\sum_i^{N^2} q_i^{\text{ahole}} = 4e$ where q_i^{ahole} is the partial anti-hole charge at the i th anti-hole lattice site. In other words a pair of a boson condensate can be accompanied within a COSB depicted in FIG 1.

Important consequence of the model outlined in this paper is that the condensation energy (U_0) of the SC state can be calculated. We will show here that within our model the primary source of U_0 is the net energy gain in IL Coulomb energy occurs due to the asymmetrical distribution of the condensed hole-charge in the adjacent layers (see FIG 1) below T_c .

Per definition U_0 is the free energy difference of the normal state and the superconducting state,

$$U_0 \approx \Delta E^{ab} + \Delta E_c^{IL}. \quad (1)$$

The ab -plane contribution to the SC condensation energy ΔE^{ab} is expected to be negligible at optimal doping. That is because our Coulomb energy calculations indicate that the ab -plane Coulomb energy in the NS and in the SC state are nearly equal and therefore the ab Coulomb energy contribution to U_0 $\Delta E_c^{ab} \approx 0$ and also the kinetic energy of the pair-condensate E_{kin}^{ab} is much smaller by several order of magnitude than IL coupling. The effective Coulomb interaction between spinless point-charges may be approximated by the expression $V_{eff}(\mathbf{r}) = e^2/(4\pi\epsilon_0\epsilon_c\mathbf{r})$, where ϵ_c takes into account phenomenologically the dielectric screening effect of the IL dielectric medium and confined hole charge [16]. For instance we get for the prototypical 5×5 lattice $\sim -1.2 \times 10^{-20}$ J ab -Coulomb energy both for the NS and for the SC COS using a simple point charge model for calculating the Coulomb energy. The details of this calculation can be found in ref. [16]. The calculated ab -kinetic energy of the 5×5 condensate is $\sim 1.1 \times 10^{-29}$ J if we use the very simple formula ("electron in a box")

$$T_{kin}^{ab} \approx \frac{\hbar^2}{2m^*} \frac{2e}{\xi_{ab}\xi_c}, \quad (2)$$

where ξ_c is the c -axis coherence length. The IL Coulomb interaction (attraction) $E_c^{IL} \approx -1.3 \times 10^{-21}$ J for the 5×5 bilayer. It must be emphasized, however, that away from optimal doping the Coulomb energy of the condensate might affect the magnitude of the condensation energy. The abrupt jump of the measured condensation energy U_0 seen in the slightly overdoped regime [22] can be attributed to the increased ΔE^{ab} contribution to U_0 .

In this article we restrict our study, however, to optimal doping and the study of the doping dependence of U_0 is planned in the near future. The main contribution to U_0 is then the IL energy gain ΔE_c^{IL} in the SC state can be given as follows,

$$U_0 \approx |E_c^{IL,NS} - E_c^{IL,SC}|. \quad (3)$$

where $E_c^{IL,NS}$ and $E_c^{IL,SC}$ are the IL Coulomb energy in the NS and in SC state. We can further simplify Eq. (3) if the NS contribution to Eq. (3) is $E_c^{IL,NS} \approx 0$, which holds if IL coupling is screened effectively in the NS (large density of the hole content in the IL space, large $\epsilon_c(NS)$). Again, if we assume $\epsilon_c \approx 33$, we get $E_c^{IL,NS} \approx +2 \times 10^{-18}$ J (12.3 eV) for a charge ordered 5×5 lattice which would be an extraordinarily large value for the IL Coulomb repulsion. Assuming, however, $\epsilon_c \approx 10000$, we get the more realistic Coulomb repulsion of $E_c^{IL,NS} \approx +10^{-22}$ J. Indeed there are measurements for cuprates which indicate large ϵ_c in the NS in the range of 10^3 to 10^5 [27]. Extraordinarily large dielectric constant has also been found recently in perovskite materials [12]. Anyhow the "relaxation" of the huge IL Coulomb repulsion in hole-doped cuprates in the NS can not easily be understood without the consideration of a large ϵ_c . Nevertheless experimental measurements and theoretical speculations

TABLE I. The calculated coherence length of the pair condensate given in a_0 using the experimental condensation energies of various cuprates and Eq. (6) at optimal doping.

	T_c (K)	$k_B T_c$ (meV)	U_0 ($\mu\text{eV}/\text{u.c.}$)	$\xi_{ab}^{calc}(a_0)$	$\xi_{ab}^{exp}(a_0)$
Bi2201	20	1.6	10^a	~ 8	
LSCO	39	2.5	21^b	~ 7	$5 - 8^c$
Tl2201	85	7	100 ± 20^d	~ 5	
Hg1201	95	7.8	$80 - 107^e$	~ 5	5^f
YBCO	92	7.5	110^g	~ 3	$3 - 4^h$
Bi2212	89	7.3	95^g	$\sim 3 - 4$	$4 - 6^i$

$a_0 \approx 3.88\text{\AA}$, U_0 is the measured condensation energy of various cuprates in μeV per unit cell at optimal doping. ^a from [28], ^b $U_0 \approx 2\text{ J/mol}$ from [18,19], ^c from [8], ^d [30], ^e $U_0 \approx 12 - 16\text{ mJ/g}$ from [20,31] and ξ_{ab} from [21], ^d $U_0 \approx 11\text{ J/mol}$ from [22], ^e $U_0 \approx 10\text{ J/mol}$ from [22], ^f from [21], ^g from [22], ⁱ from recent measurements of Wang *et al.*, $\xi_{ab} \approx 23\text{\AA} (\sim 5 - 6a_0)$ [10], from STM images of ref. [14] $\xi_{ab} \approx 4a_0$, ^h from [8], ξ_{ab}^{calc} is calculated according to Eq. (6) and is also given in Table I and ξ_{ab}^{exp} is the measured in-plane coherence length given in $a_0 \approx 3.9\text{\AA}$. The notations are as follows for the compounds: Bi2201 is $\text{Bi}_2\text{Sr}_2\text{CuO}_{6+\delta}$, LSCO ($\text{La}_{1.85}\text{Sr}_{0.15}\text{CuO}_4$), Tl2201 ($\text{Tl}_2\text{Ba}_2\text{CuO}_6$), Hg1201 ($\text{HgBa}_2\text{CuO}_{4+\delta}$), YBCO (YBa_2CuO_7) and Bi2212 is $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$.

suggest that ϵ_c in cuprates and in other materials with perovskite structure is strongly temperature and doping dependent [11]. The sharp decrease of ϵ_c below T_c should also be explained within our bilayer model by the pair-condensation of the hole-content to the sheets. This is what can be seen in the c -axis optical spectra of cuprates [6,24]. The lack of the c -axis plasma edge in the NS is an obvious experimental evidence of the strong temperature dependence of ϵ_c . Then we have

$$2(n+1)N^2U_0 \approx E_c^{IL,SC}, \quad (4)$$

where $E_c^{IL,SC}$ is the Coulomb energy gain in the SC state. U_0 is the experimental condensation energy given per unit cell. Eq. (4) is generalized for multilayer cuprates introducing n . For single layer cuprates $n = 0$, for bilayers $n = 1$, etc.

Inter-layer Coulomb coupling can be a natural source of the condensation energy and of HTSC. Checkerboard-like charge pattern (COS) seen experimentally [14,15] directly leads to IL energy gain and to potential energy driven condensation energy if the hole-anti hole charge pattern is asymmetrically condensed to the adjacent layers (FIG 1). Assuming that thermal equilibrium occurs at T_c for the competing charge ordered phases of the NS and the SC state the following equation for the condensation energy can be formulated using Eq. (4),

$$2(n+1)N^2U_0 \approx 2(n+1) \left[\frac{\xi_{ab}}{a_0} + 1 \right]^2 U_0 \approx k_B T_c, \quad (5)$$

where k_B is the Boltzmann constant.

At a first look this formula seems to be unusual because of the dependence of the condensation energy on

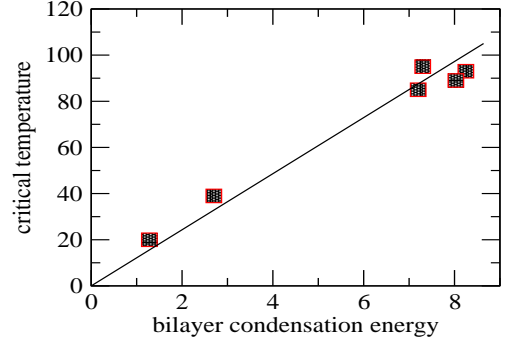


FIG. 2. The critical temperature (K) at optimal doping as a function of the bilayer condensation energy $2(n+1)N^2U_0$, meV using Eq. (5). The straight line is a linear fit to the data. The slope of the linear fit is k_B which is a strong evidence of Eq. (5).

T_c . The available measurements of the condensation energy on various cuprates show no correlation of U_0 with the critical temperature. One of the important goals of this paper, however, to show that correlation can indeed be found with T_c if T_c is plotted against $2(n+1)N^2U_0$ (the bilayer condensation energy, FIG 2). In other words *the condensation energy of the COSB system shows correlation with T_c* . In order to test the validity of Eq. (5) we estimate the coherence length of the pair condensate using Eqs. (5) and using only experimental data,

$$\xi_{ab} \approx a_0 \left[\sqrt{\frac{k_B T_c}{2(n+1)U_0}} - 1 \right] \quad (6)$$

The results are given in Table I as ξ_{ab}^{calc} and compared with the available measured ξ_{ab}^{exp} . The agreement is excellent which strongly suggests that Eq. (6) should also work for other cuprates. The validity of Eq. (5) is clearly clarified in FIG 2 using mostly experimental information for ξ_{ab} , T_c and U_0 (values are given in Table I). For Tl2201 no measured ξ_{ab} is found in the literature, therefore the estimated ξ_{ab} is used (given in Table I). We will show that using this estimated value of $N = 6(\xi_{ab} \approx 5a_0)$ we predict ϵ_c in nice agreement with optical measurements for Tl2201. *Remarkable feature of FIG 2 is that the slope of the linear fit to the measured data points is precisely k_B which supports Eq. (5)*. The underlying physics of HTSC seems to be reflected by Eq. (5): the equation couples the basic observable quantities T_c , U_0 and ξ_{ab} . We predict for the multilayer Hg-cuprates, Hg1212 ($T_c = 126\text{ K}$) and Hg1223 ($T_c = 135\text{ K}$) the condensation energies 146 and 117 $\mu\text{eV}/\text{u.c.}$ ($\xi_{ab} \approx 4a_0$ [21]), respectively using Eq. (5).

The expression Eq. (5) leads to the very simple formula for the critical temperature using Eq. (4) and a simple Coulomb expression for the IL coupling energy $E_c^{IL,SC}$ [16] ($T_c \approx k_B^{-1} E_c^{IL,SC}$)

TABLE II. The calculated dielectric constant ϵ_c using Eq. (8) in various cuprates at the calculated coherence length ξ_{ab} of the charge ordered state given in Table I.

	$d(\text{\AA})$	$T_c(K)$	$\xi_{ab}^{calc}(a_0)$	ϵ_c	ϵ_c^{exp}
Bi2201	12.2	20	8	9.9	12 ^a
LSCO	6.65	39	7	11.3	23 ± 3, 13.5 ^b
Hg1201	9.5	95	5	6.5	
Tl2201	11.6	85	5	13.0	11.3 ^c
YBCO	8.5	93	3	19.4	23.6 ^d

where ξ_{ab}^{calc} is the estimated in-plane coherence length given in $a_0 \approx 3.9\text{\AA}$ unit. d is the CuO_2 plane to plane inter-layer distance in \AA , T_c is the experimental critical temperature. ϵ_c is from Eq. (8). ϵ_c^{exp} are the measured values obtained from the following references: ^a [25], ^b [26], or from reflectivity measurements [30], $\omega_p \approx 55\text{cm}^{-1}$ [33], $\lambda_c \approx 3\mu\text{m}$ [31], ^c from [30], ^d from reflectivity measurements: $\omega_p \approx 60\text{cm}^{-1}$ [33], $\lambda_c \approx 0.9\mu\text{m}$ [13].

$$T_c(N, d, \epsilon_c) \approx \frac{e^2}{4\pi\epsilon_0\epsilon_c k_B} \sum_{n=1}^2 \sum_{m=2}^{N_l} \sum_{ij}^{N^2} \frac{q_i^{(n)} q_j^{(m)}}{r_{ij}^{(n,m)}} \quad (7)$$

where $r_{ij}^{(n,m)}$ is the inter-point charge distance and $r_{ij}^{(n,m)} \geq d_{IL}$, where d_{IL} is the IL distance (CuO_2 plane to plane, $i \neq j$). n, m represent layer indexes ($n \neq m$). First the summation goes within the bilayer up to N^2 then the IL Coulomb interaction of the basal bilayer are calculated with other layers along the c -axis in both direction ($n = 1, 2$) [16]. N_l is the number of layers along the c -axis. When $N_l \rightarrow \infty$, bulk T_c is calculated. T_c can also be calculated for thin films when N_l is finite. ϵ_c can also be derived

$$\epsilon_c \approx \frac{e^2}{4\pi\epsilon_0 k_B T_c} \sum_{n=1}^2 \sum_{m=2}^{N_l} \sum_{ij}^{N^2} \frac{q_i^{(n)} q_j^{(m)}}{r_{ij}^{(n,m)}} \quad (8)$$

where a c -axis average of ϵ_c is computed when $N_l \rightarrow \infty$.

The calculation of the c -axis dielectric constants ϵ_c might provide further evidences for Eq. (5) when compared with the measured values [11,26]. In Table II we have calculated the static dielectric function ϵ_c using Eq. (8) and compared with the experimental impedance measurements [27,26]. ϵ_c can also be extracted from the c -axis optical measurements using the relation [30] $\epsilon_c(\omega) = \epsilon_c(\infty) - c^2/(\omega_p^2 \lambda_c^2)$, where ϵ_∞ and ω_p are the high-frequency dielectric constant and the plasma frequency, respectively [34]. c and λ_c are the speed of light and the c -axis penetration depth. At zero crossing $\epsilon_c(\omega) = 0$ and $\omega_p = c/(\lambda_c \epsilon_c^{1/2}(\infty))$. Using this relation we predict for the single layer Hg1201 the low plasma frequency of $\omega_p \approx 8\text{cm}^{-1}$ using $\epsilon_c = \epsilon_c(\infty) \approx 6.5$ (Table II) and $\lambda_c \approx 8\mu\text{m}$ [31].

If the physical picture derived from our model is correct, it should be a guide for further experimental studies aiming to improve SC in cuprates or in other materials. This can be done by tuning the IL distance and ϵ_c in these materials. The application of this model to other

class of HTSC materials, such as fullerides or MgB_2 is expected to be also effective.

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